

<b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b>				Docket Number		Application Number	
				M4065.133/P133-B		Not Yet Assigned	
				Applicant(s)			
				Brian Vaartstra and Donald Westmoreland			
				Filing Date		Group Art Unit	
<b>U.S. PATENT DOCUMENTS</b>							
*EXAMINER INITIAL	REF	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
* CX	A	5,567,964	10/22/96	Kashihara et al.			9/11/95
* CX	B	5,688,724	11/18/97	Yoon et al.			12/23/94
* CX	C	5,406,447	4/11/95	Miyazaki			12/29/92
* CX	D	5,362,632	11/8/94	Mathews			2/8/94
* CX	E	5,690,727	11/25/97	Azuma et al.			1/27/97
* CX	F	5,568,352	10/22/96	Hwang			11/16/95
* CX	G	5,686,339	11/11/97	Lee et al.			7/30/96
* CX	H	5,679,980	10/21/97	Summerfelt			12/19/96
* CX	I	5,142,438	8/25/92	Reinberg et al.			11/15/91
* CX	J	5,696,018	12/9/97	Summerfelt et al.			6/7/95
* CX	K	5,504,041	4/2/96	Summerfelt			8/1/94
* CX	L	5,665,628	9/9/97	Summerfelt			6/7/95
* CX	M	5,585,300	12/17/96	Summerfelt			8/1/94
* CX	N	5,187,638	2/16/93	Sandhu et al.			7/27/92
* CX	O	5,198,386	3/30/93	Gonzalez			6/8/92
* CX	P	5,464,786	11/7/95	Figura et al.			10/24/94
* CX	Q	5,478,772	12/26/95	Fazan			2/17/95
* CX	R	5,498,562	3/12/96	Dennison et al.			4/29/94
* CX	S	5,506,166	4/9/96	Sandhu et al.			9/27/94
* CX	T	5,605,857	2/25/97	Jost et al.			2/22/95
* CX	U	5,654,222	8/5/97	Sandhu et al.			5/17/95
* CX	V	5,654,224	8/5/97	Figura et al.			7/25/96
* CX	W	5,663,088	9/2/97	Sandhu et al.			5/19/95
* CX	X	5,717,250	2/10/98	Schuele et al.			3/7/96
* CX	Y	5,760,474	6/2/98	Schuele			7/9/96
* CX	Z	6,090,697	7/18/00	Xing et al.			
* CX	A1	6,294,420	9/2001	Tsu et al.			
* CX	B1	6,365,527	4/2002	Lu et al.			
* CX	C1	5,489,548	2/1996	Nishioka et al.			
* CX	D1	5,834,803	11/1998	Hashimoto, Keiichi			
* CX	E1	5,895,938	4/1999	Watanabe et al.			
* CX	F1	5,486,492	1/1996	Yamamoto et al.			
* CX	G1	6,320,213	11/2001	Kirlin et al.			
* CX	H1	6,455,419	09/2002	Konecni et al.			
* CX	I1	6,194,754	02/2001	Aggarwal et al.			
* CX	J1	5,414,301	5/1995	Thomas, Michael E.			
* CX	K1	5,899,740	5/1999	Kwon, Chul-soon			
* CX	L1	6,054,331	4/2000	Woo et al.			
* CX	M1	6,100,200	8/2000	Van Buskirk et al.			
* CX	N1	5,851,896	12/1998	Summerfelt, Scott R.			
* CX	O1	6,284,646	9/2001	Leem, Hyeun-Seog			
* CX	P1	6,580,111	6/2003	Kim et al.			

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	Filing Date 8/19/03	Group Art Unit

## FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translations	
							YES	NO
* <i>OK</i>	AA	EP 0 770 862 A1	02.05.1997	Europe			X	

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

* <i>OK</i>	BB	Matsushita et al., <i>Optimum Electrode Materials for Ta<sub>2</sub>O<sub>3</sub> Capacitors at High and Low Temperature Processes</i> , Extended Abstract of the 1993 International Conference on Solid State Devices and Materials, Makuhari, 1993, pp. 853-855.						
* <i>OK</i>	CC	Kwon, et al., <i>Degradation-Free Ta<sub>2</sub>O<sub>5</sub> Capacitor after BPSG Reflow at 850°C for High Density DRAMs</i> , IEEE, 1993, pp. 53-56.						
* <i>OK</i>	DD	Shappirio, et al., <i>Diboride Diffusion Barriers in Silicon and GaAs Technology</i> , J. Vac. Sci. Technol. B, Vol. 4, No. 6, Nov/Dec 1986, pp. 1409-1415.						
* <i>OK</i>	EE	Rebhoiz, et al., <i>Structure, Mechanical and Tribological Properties of Ti-B-N and Ti-Al-B-N Multiphase Thin Films Produced by Electron-Beam Evaporation</i> , J. Vac. Sci. Technol. A 16(5), Sep/Oct 1998, pp. 2850-2857.						

EXAMINER: <i>Christy Hancek</i>	DATE CONSIDERED: 2/23/04
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	